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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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EOL announced Product

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MOS FIELD EFFECT TRANSISTOR

2SK3058

SWITCHING

N-CHANNEL POWER MOS FET

INDUSTRIAL USE

DESCRIPTION

This product is N-Channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Super Low On-State Resistance
 $R_{DS(on)1} = 17 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 28 \text{ A)}$
 $R_{DS(on)2} = 27 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.0 \text{ V, } I_D = 28 \text{ A)}$
- Low C_{iss} : $C_{iss} = 2100 \text{ pF (TYP.)}$
- Built-in Gate Protection Diode

ABSOLUTE MAXIMUM RATINGS ($T_A = 25 \text{ }^\circ\text{C}$)

Drain to Source Voltage ($V_{GS} = 0$)	V_{DSS}	60	V
Gate to Source Voltage ($V_{DS} = 0$)	$V_{GSS(AC)}$	± 20	V
Gate to Source Voltage ($V_{DS} = 0$)	$V_{GSS(DC)}$	+20, -10	V
Drain Current (DC)	$I_D(DC)$	± 55	A
Drain Current (Pulse) ^{Note1}	$I_D(\text{pulse})$	± 165	A
Total Power Dissipation ($T_C = 25^\circ\text{C}$)	P_T	58	W
Total Power Dissipation ($T_A = 25^\circ\text{C}$)	P_T	1.5	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to + 150	$^\circ\text{C}$
Single Avalanche Current ^{Note2}	I_{AS}	27.5	A
Single Avalanche Energy ^{Note2}	E_{AS}	75.6	mJ

Notes 1. $PW \leq 10 \mu\text{s}$, Duty cycle $\leq 1 \%$

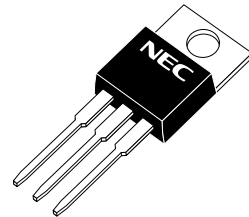
2. Starting $T_{ch} = 25 \text{ }^\circ\text{C}$, $V_{DD} = 30 \text{ V}$, $R_G = 25 \Omega$, $V_{GS} = 20 \text{ V} \rightarrow 0$

ORDERING INFORMATION

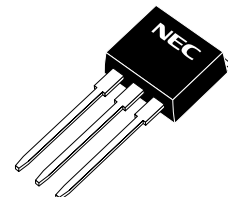
PART NUMBER	PACKAGE
2SK3058	TO-220AB
2SK3058-S	TO-262
2SK3058-ZJ	TO-263
★ 2SK3058-Z	TO-220SMD ^{Note}

Note TO-220SND package is produced only in Japan.

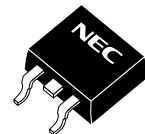
(TO-220AB)



(TO-262)



(TO-263, TO-220SMD)



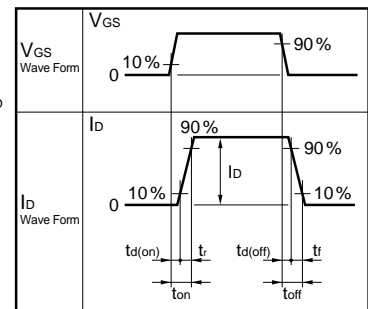
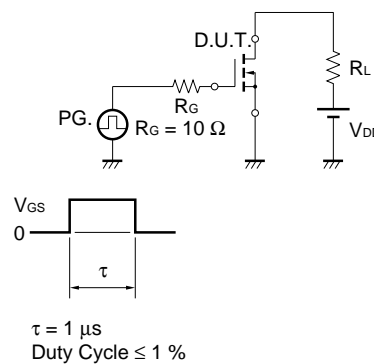
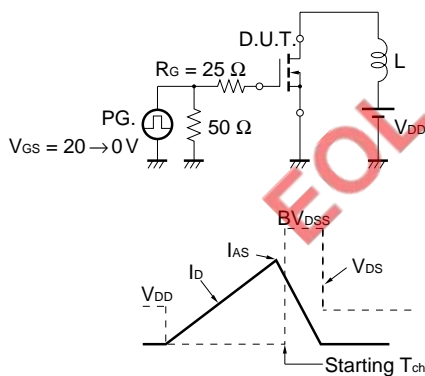
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ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

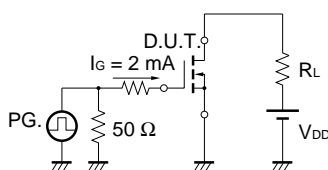
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	R _{DS(on)1}	V _{GS} = 10 V, I _D = 28 A		12	17	mΩ
	R _{DS(on)2}	V _{GS} = 4.0 V, I _D = 28 A		19	27	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.0	1.6	2.0	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 28 A	13	42		S
Drain Leakage Current	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V			10	μA
Gate to Source Leakage Current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μA
Input Capacitance	C _{iss}	V _{DS} = 10 V		2100		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		550		pF
Reverse Transfer Capacitance	C _{rss}	F = 1 MHz		220		pF
Turn-on Delay Time	t _{d(on)}	I _D = 28 A		36		ns
Rise Time	t _r	V _{GS} = 10 V		410		ns
Turn-off Delay Time	t _{d(off)}	V _{DD} = 30 V		130		ns
Fall Time	t _f	R _G = 10 Ω		260		ns
Total Gate Charge	Q _G	I _D = 55 A		45		nC
Gate to Source Charge	Q _{GS}	V _{DD} = 48 V		7		nC
Gate to Drain Charge	Q _{GD}	V _{GS} = 10 V		13		nC
Body Diode Forward Voltage	V _{F(S-D)}	I _F = 55 A, V _{GS} = 0 V		1.0		V
Reverse Recovery Time	t _{rr}	I _F = 55 A, V _{GS} = 0 V		60		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 100A/μs		100		nC

TEST CIRCUIT 1 AVALANCHE CAPABILITY

★ TEST CIRCUIT 2 SWITCHING TIME

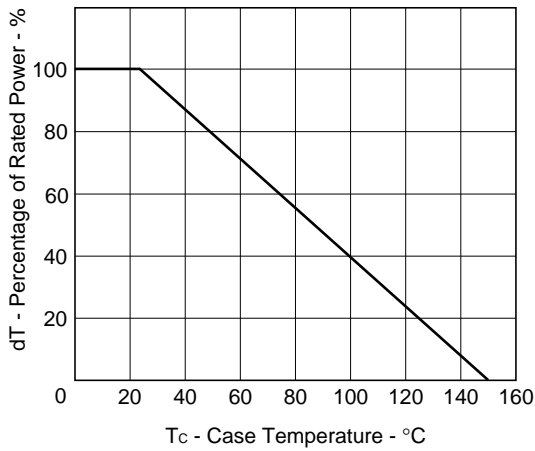


TEST CIRCUIT 3 GATE CHARGE

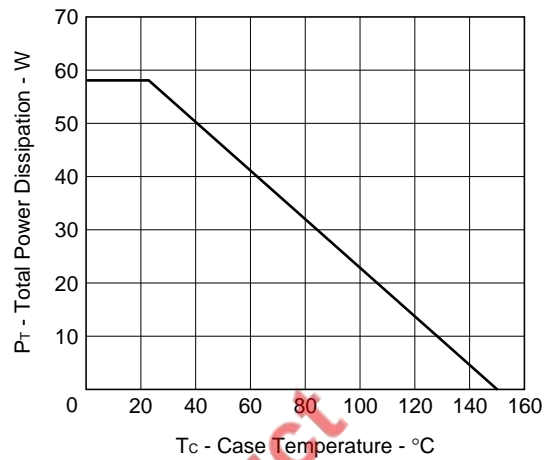


TYPICAL CHARACTERISTICS (T_A = 25 °C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

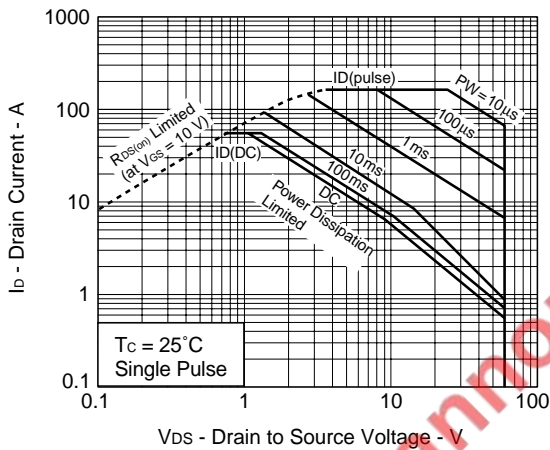


TOTAL POWER DISSIPATION vs. CASE TEMPERATURE

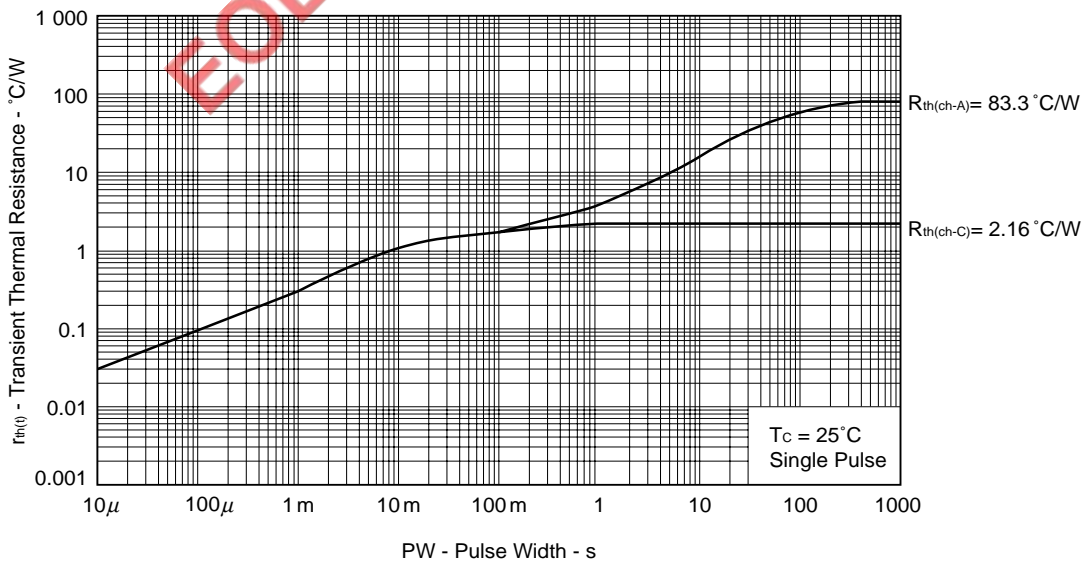


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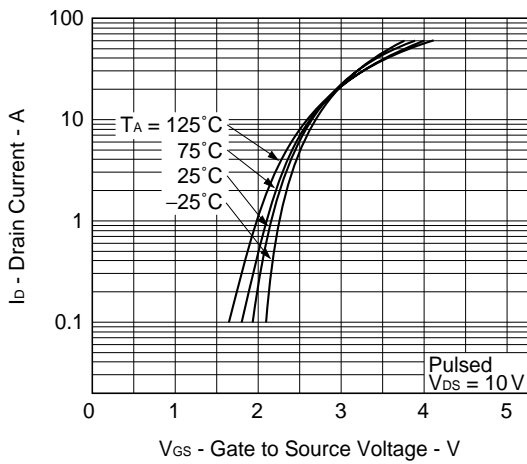
FORWARD BIAS SAFE OPERATING AREA



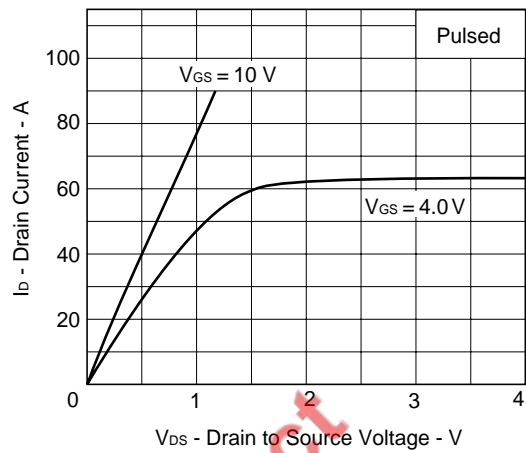
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



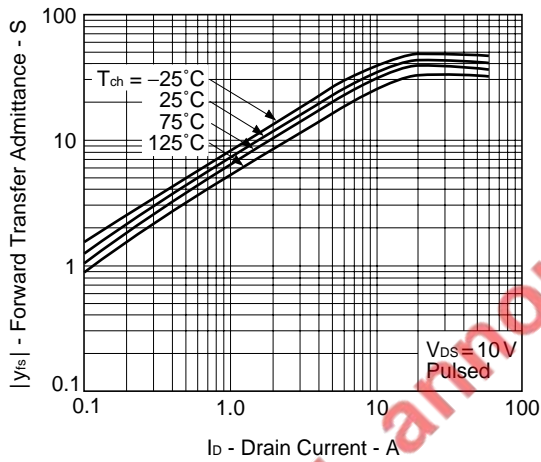
FORWARD TRANSFER CHARACTERISTICS



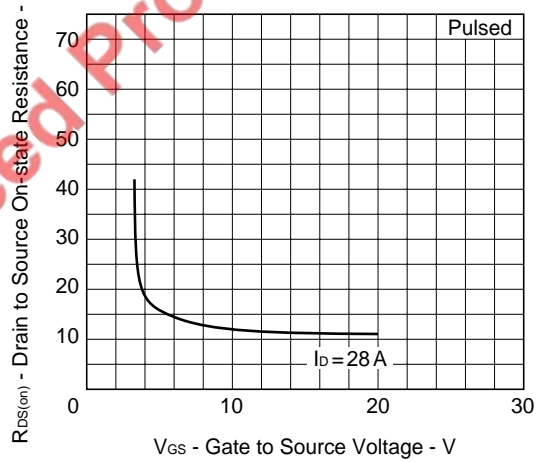
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



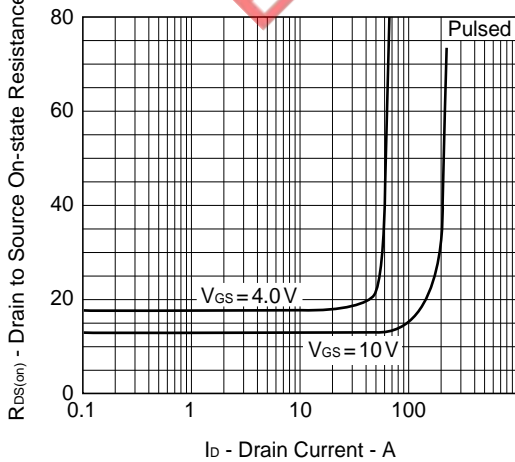
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



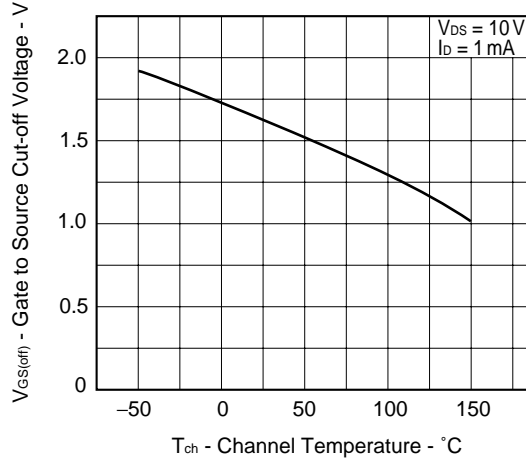
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



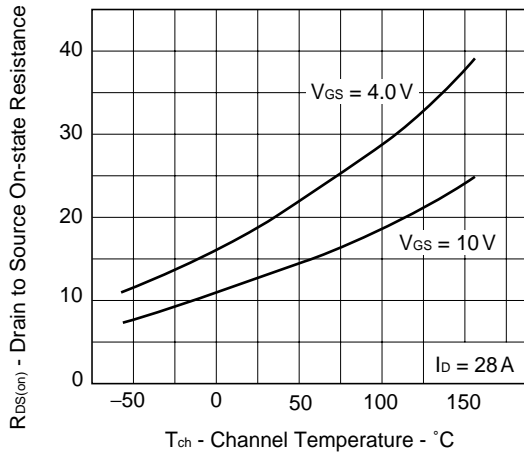
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

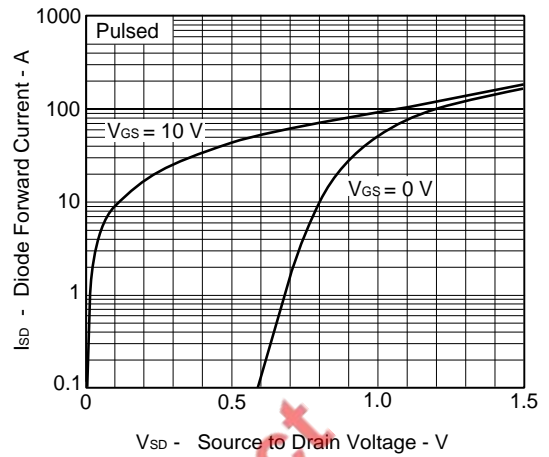


DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

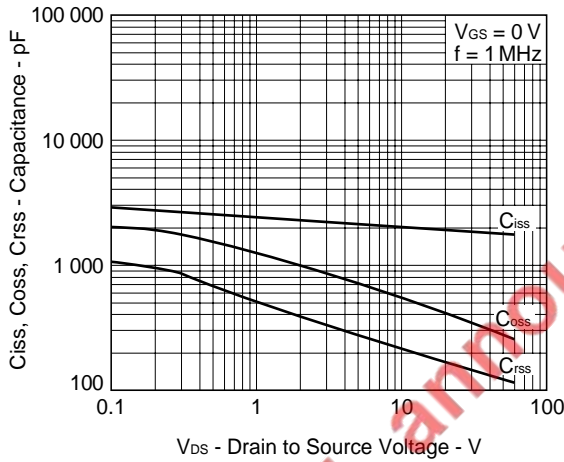


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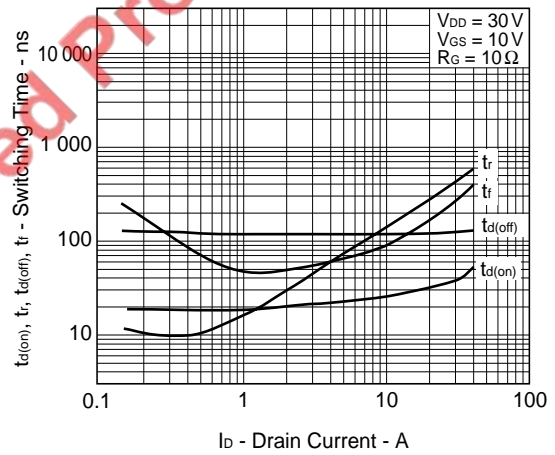
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



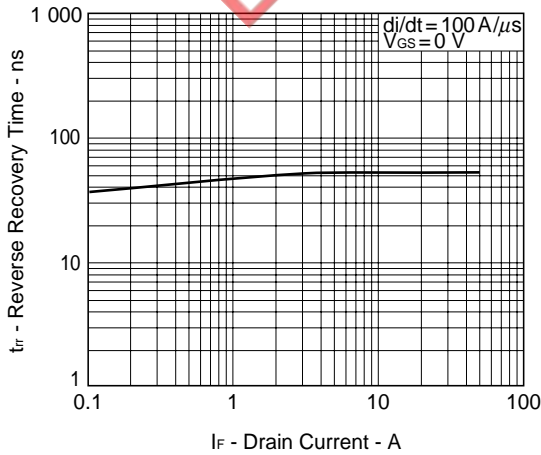
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



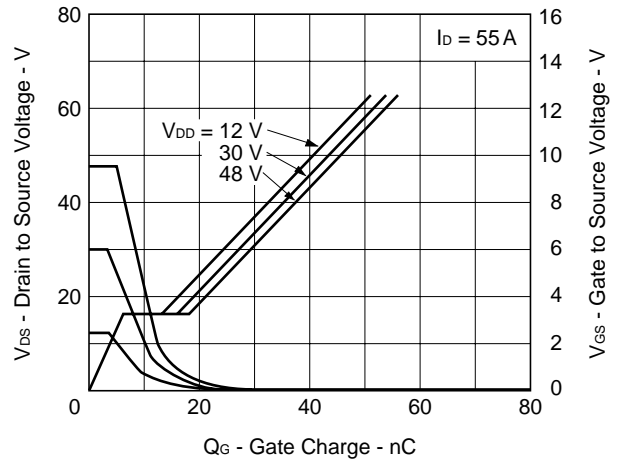
SWITCHING CHARACTERISTICS



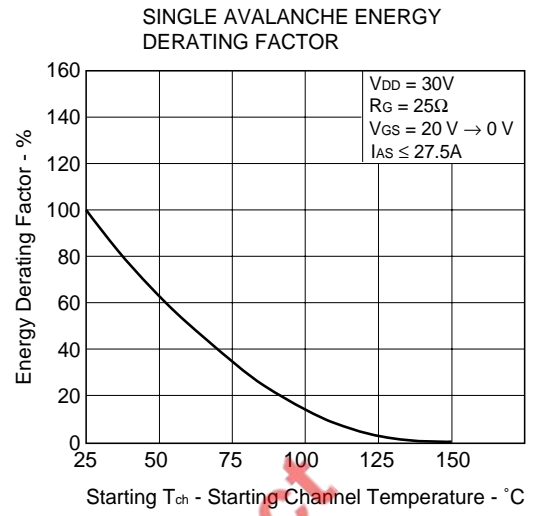
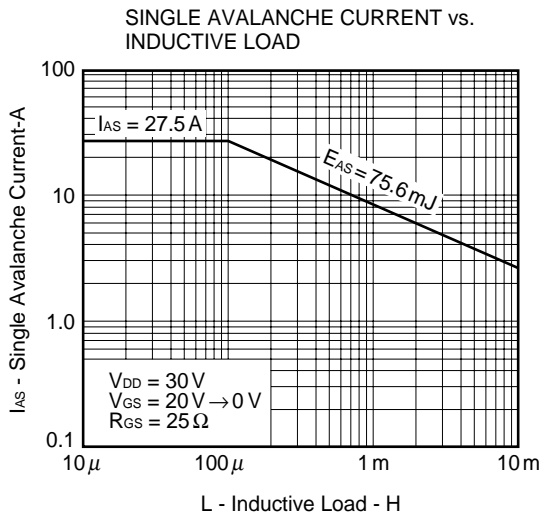
REVERSE RECOVERY TIME vs. DRAIN CURRENT



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



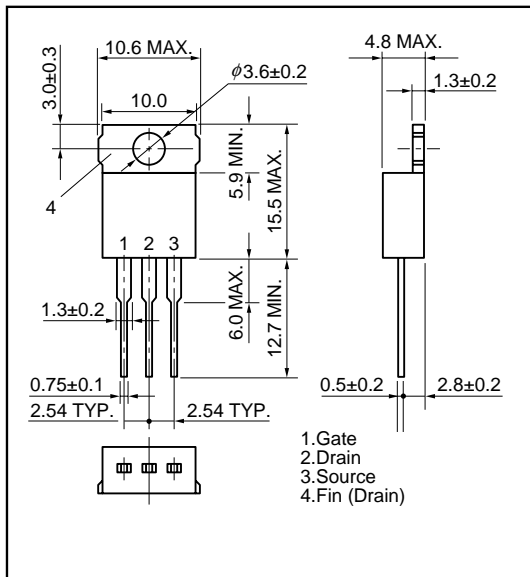
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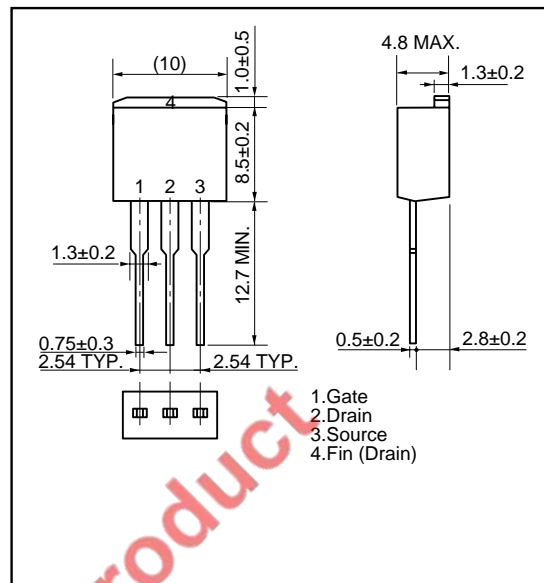
EOL announced Product

PACKAGE DRAWINGS (Unit : mm)

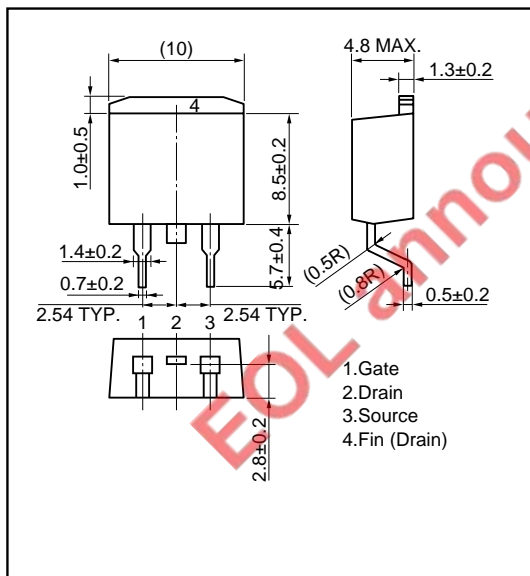
1)TO-220AB (MP-25)



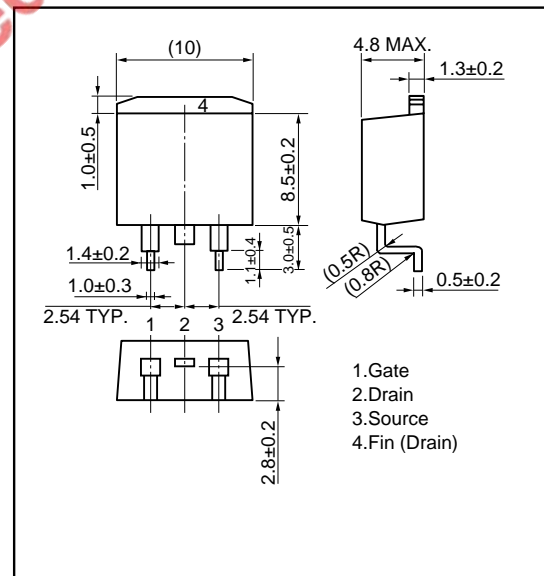
2)TO-262 (MP-25 Fin Cut)



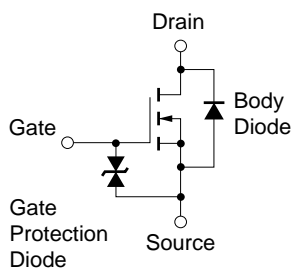
3)TO-263 (MP-25ZJ)



★ 3)TO-220SMD (MP-25Z)^{Note}



EQUIVALENT CIRCUIT



Note This package is produced only in Jaman.

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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